DL PACKAGE

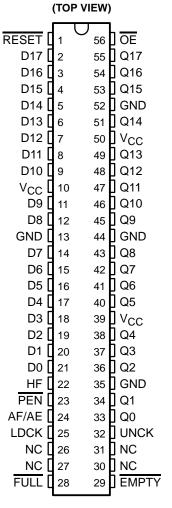
SCAS204A – APRIL 1992 – REVISED SEPTEMBER 1995

- Member of the Texas Instruments Widebus™ Family
- Load Clock and Unload Clock Can Be Asynchronous or Coincident
- 512 Words by 18 Bits
- Low-Power Advanced CMOS Technology
- Full, Empty, and Half-Full Flags
- Programmable Almost-Full/Almost-Empty Flag
- Fast Access Times of 15 ns With a 50-pF Load and All Data Outputs Switching Simultaneously
- Data Rates From 0 to 50 MHz
- 3-State Outputs
- Pin Compatible With SN74ACT7806 and SN74ACT7814
- Packaged in Shrink Small-Outline 300-mil (DL) Package Using 25-mil Center-to-Center Spacing

description

A FIFO memory is a storage device that allows data to be written into and read from its array at independent data rates. The SN74ACT7804 is a 512-word by 18-bit FIFO for high speed and fast access times. It processes data at rates up to 50 MHz and access times of 15 ns in a bit-parallel format.

Data is written into memory on a low-to-high transition at the load-clock (LDCK) input and is read out on a low-to-high transition at the unload-clock (UNCK) input. The memory is full when the number of words clocked in exceeds the



NC - No internal connection

number of words clocked out by 512. When the memory is full, LDCK signals have no effect on the data residing in memory. When the memory is empty, UNCK signals have no effect.

Status of the FIFO memory is monitored by the full ($\overline{\text{FULL}}$), empty ($\overline{\text{EMPTY}}$), half-full (HF), and almost-full/almost-empty (AF/AE) flags. The $\overline{\text{FULL}}$ output is low when the memory is full and high when the memory is not full. The $\overline{\text{EMPTY}}$ output is low when the memory is empty and high when it is not empty. The HF output is high when the FIFO contains 256 or more words and is low when it contains 255 or less words. The AF/AE status flag is a programmable flag. The first one or two low-to-high transitions of LDCK after reset are used to program the almost-empty offset value (X) and the almost-full offset value (Y) if program enable ($\overline{\text{PEN}}$) is low. The AF/AE flag is high when the FIFO contains X or less words or (512 – Y) or more words. The AF/AE flag is low when the FIFO contains between (X + 1) and (511 – Y) words.



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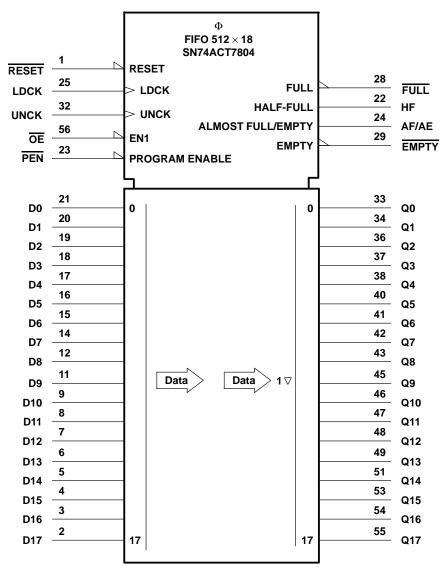
description (continued)

A low level on the reset (RESET) input resets the internal stack pointers and sets FULL high, AF/AE high, HF low, and EMPTY low. The Q outputs are not reset to any specific logic level. The FIFO must be reset upon power up.

The first word loaded into empty memory causes $\overline{\text{EMPTY}}$ to go high and the data to appear on the Q outputs. It is important to note that the first word does not have to be unloaded. The data outputs are noninverting with respect to the data inputs and are in the high-impedance state when the output-enable $(\overline{\text{OE}})$ input is high.

The SN74ACT7804 is characterized for operation from 0°C to 70°C.

logic symbol†

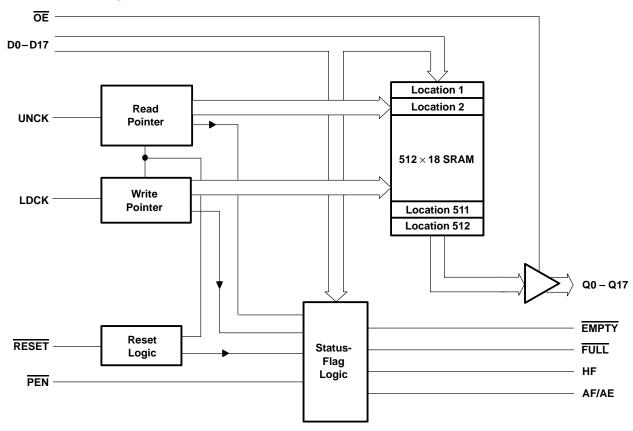


[†]This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



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functional block diagram



Terminal Functions

TE	TERMINAL		TERMINAL I/O		DESCRIPTION				
NAME	NO.	1/0	DESCRIPTION						
AF/AE	24	0	Almost-full/almost-empty flag. Depth-offset values can be programmed for AF/AE, or the default value of 64 can be used for both the almost-empty offset (X) and the almost-full offset (Y). AF/AE is high when memory contains X or less words or (512 – Y) or more words. AF/AE is high after reset.						
D0-D17	2-9, 11-12, 14-21	ı	18-bit data input port						
EMPTY	29	0	Empty flag. EMPTY is low when the FIFO is empty. A FIFO reset also causes EMPTY to go low.						
FULL	28	0	Full flag. FULL is low when the FIFO is full. A FIFO reset causes FULL to go high.						
HF	22	0	Half-full flag. HF is high when the FIFO memory contains 256 or more words. HF is low after reset.						
LDCK	25	-	Load clock. Data is written to the FIFO on the rising edge of LDCK when FULL is high.						
ŌĒ	56	-	Output enable. When OE is high, the data outputs are in the high-impedance state.						
PEN	23	ı	Program enable. After reset and before the first word is written to the FIFO, the binary value on D0–D7 is latched as an AF/AE offset value when PEN is low and LDCK is high.						
Q0-Q17	33-34, 36-38, 40-43, 45-49, 51, 53-55	0	18-bit data output port						
RESET	1	ı	Reset. A low level on RESET resets the FIFO and drives AF/AE and FULL high and HF and EMPTY low.						
UNCK	32	Ī	Unload clock. Data is read from the FIFO on the rising edge of UNCK when EMPTY is high.						



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offset values for AF/AE

The almost-full/almost-empty flag has two programmable limits: the almost-empty offset value (X) and the almost-full offset value (Y). They can be programmed after the FIFO is reset and before the first word is written to memory. The AF/AE flag is high when the FIFO contains X or less words or (512 - Y) or more words.

To program the offset values, \overline{PEN} can be brought low after reset only when LDCK is low. On the following low-to-high transition of LDCK, the binary value on D0 –D7 is stored as the almost-empty offset value (X) and the almost-full offset value (Y). Holding \overline{PEN} low for another low-to-high transition of LDCK reprograms Y to the binary value on D0–D7 at the time of the second LDCK low-to-high transition. Writes to the FIFO memory are disabled while the offsets are programmed. A maximum value of 255 can be programmed for either X or Y (see Figure 1). To use the default values of X = Y = 64, \overline{PEN} must be held high.

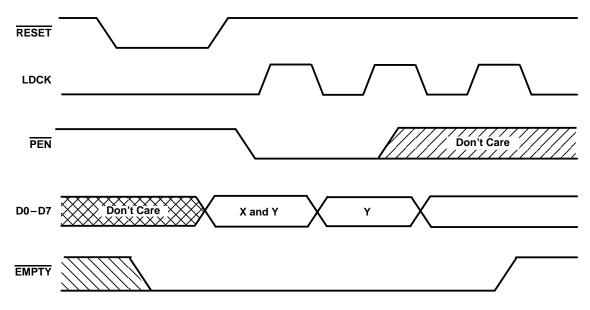


Figure 1. Programming X and Y Separately



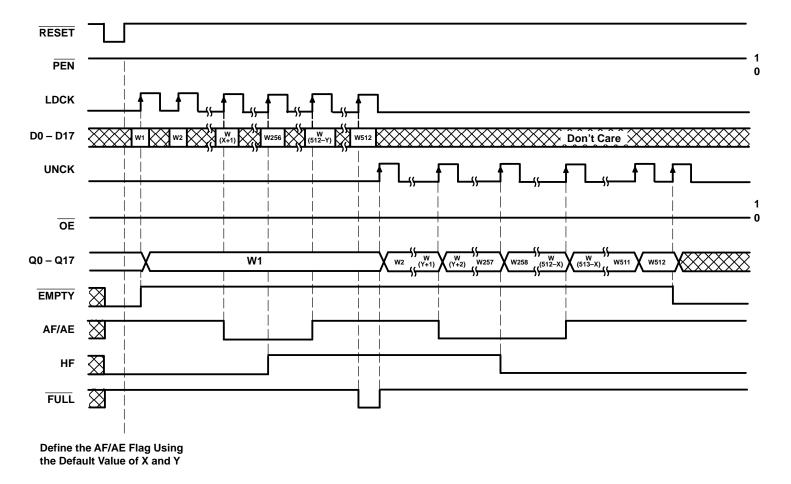


Figure 2. Write, Read, and Flag Timing Reference

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range, V _{CC}	0.5 V to 7 V
nput voltage, V _I	7 V
Voltage applied to a disabled 3-state output	5.5 V
Operating free-air temperature range, TA	0°C to 70°C
Storage temperature range, Teta	-65°C to 150°C

recommended operating conditions

			'ACT78	'ACT7804-20		'ACT7804-25		'ACT7804-40	
			MIN	MAX	MIN	MAX	MIN	MAX	UNIT
VCC	Supply voltage		4.5	5.5	4.5	5.5	4.5	5.5	V
V _{IH}	High-level input voltage		2		2		2		V
V _{IL}	Low-level input voltage			0.8		0.8		0.8	V
ЮН	High-level output current	Q outputs, Flags		-8		-8		-8	mA
1	Low lovel output ourrent	Q outputs		16		16		16	^
IOL	Low-level output current	Flags		8		8		8	mA
f _{clock}	Clock frequency	•		50		40		25	MHz
	Pode a describer	LDCK high or low	7		8		12		
		UNCK high or low	7		8		12		
t _W	Pulse duration	PEN low	7		8		12		ns
		RESET low	10		10		12		
		D0-D17 before LDCK↑	5		5		5		
t _{su}	Setup time	PEN before LDCK↑	5		5		5		ns
		LDCK inactive before RESET high	5		6		6		
		D0-D17 after LDCK↑	0		0		0		
4.	Hald the a	LDCK inactive after RESET high	5		6		6		
^t h	Hold time	PEN low after LDCK↑	3		3		3		ns
		PEN high after LDCK↓	0		0		0		
T _A	Operating free-air temperat	ure	0	70	0	70	0	70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS			TYP‡	MAX	UNIT
Vон		$V_{CC} = 4.5 \text{ V},$	$I_{OH} = -8 \text{ mA}$	2.4			V
Flags		$V_{CC} = 4.5 \text{ V},$	$I_{OL} = 8 \text{ mA}$			0.5	V
VOL	Q outputs	$V_{CC} = 4.5 \text{ V},$	I _{OL} = 16 mA			0.5	V
lį		$V_{CC} = 5.5 \text{ V},$	$V_I = V_{CC}$ or 0			±5	μΑ
loz		V _{CC} = 5.5 V,	VO = VCC or 0			±5	μΑ
ICC		V _{CC} = 5.5 V,	$V_{I} = V_{CC} - 0.2 \text{ V or } 0$			400	μΑ
∆lCC§		V _{CC} = 5.5 V,	One input at 3.4 V, Other inputs at V _{CC} or GND			1	mA
Ci		V _I = 0,	f = 1 MHz		4		pF
Со		$V_{O} = 0$,	f = 1 MHz		8		pF

[‡] All typical values are at V_{CC} = 5 V, T_A = 25°C. § This is the supply current for each input that is at one of the specified TTL voltage levels rather 0 V or V_{CC}.



[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

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switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF (unless otherwise noted) (see Figures 5 and 6)

PARAMETER	FROM	то	'ACT7804-20			'ACT7804-25		'ACT7804-40		UNIT
PARAMETER	(INPUT)	(OUTPUT)	MIN	TYP [†]	MAX	MIN	MAX	MIN	MAX	UNIT
f _{max}	LDCK or UNCK		50			40		25		MHz
t _{pd}	LDCK↑		9		20	9	22	9	24	
t _{pd}	UNCK↑	Any Q	6	11.5	15	6	18	6	20	ns
t _{pd} ‡	UNCK↑			10.5						
^t PLH	LDCK↑		6		15	6	17	6	19	
^t PHL	UNCK↑	EMPTY	6		15	6	17	6	19	ns
^t PHL	RESET low		4		16	4	18	4	20	
^t PHL	LDCK↑		6		15	6	17	6	19	
^t PLH	UNCK↑	FULL	6		15	6	17	6	19	ns
t _{PLH}	RESET low		4		18	4	20	4	22	
t _{pd}	LDCK↑		7		18	7	20	7	22	
t _{pd}	UNCK↑	AF/AE	7		18	7	20	7	22	ns
t _{PLH}	RESET low		2		10	2	12	2	14	
t _{PLH}	LDCK↑		5		18	5	20	5	22	
t _{PHL}	UNCK↑	HF	7		18	7	20	7	22	ns
tPHL	RESET low		3		12	3	14	3	16	
t _{en}	ŌĒ	Any Q	2		9	2	10	2	11	ns
t _{dis}	OL	Ally Q	2		10	2	11	2	12	115

[†] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

operating characteristics, V_{CC} = 5 V, T_A = 25°C

	PARAMETER		TEST CON	IDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance per FIFO channel	Outputs enabled	C _L = 50 pF,	f = 5 MHz	53	pF

[‡] This parameter is measured at $C_L = 30 \text{ pF}$ (see Figure 3).

TYPICAL CHARACTERISTICS

PROPAGATION DELAY TIME LOAD CAPACITANCE

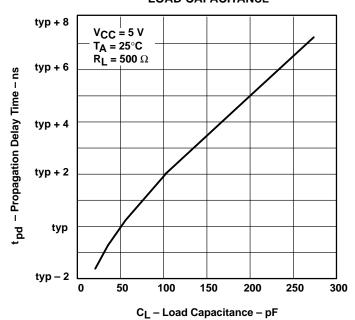


Figure 3

SUPPLY CURRENT CLOCK FREQUENCY

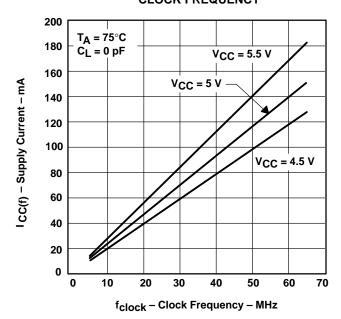


Figure 4



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TYPICAL CHARACTERISTICS

calculating power dissipation

With $I_{CC(f)}$ taken from Figure 4, the maximum power dissipation (P_T) based on all data outputs changing states on each read can be calculated by:

$$\mathsf{P}_\mathsf{T} = \mathsf{V}_\mathsf{CC} \times [\mathsf{I}_\mathsf{CC}(\mathsf{f}) + (\mathsf{N} \times \Delta \mathsf{I}_\mathsf{CC} \times \mathsf{dc})] + \Sigma (\mathsf{C}_\mathsf{L} \times \mathsf{V}_\mathsf{CC}^2 \times \mathsf{f}_\mathsf{o})$$

A more accurate power calculation based on device use and average number of data outputs switching can be found by:

$$P_T = V_{CC} \times [I_{CC} + (N \times \Delta I_{CC} \times dc)] + \Sigma (C_{pd} \times V_{CC}^2 \times f_i) + \Sigma (C_L \times V_{CC}^2 \times f_o)$$

where:

 I_{CC} = power-down I_{CC} maximum

N = number of inputs driven by a TTL device

 ΔI_{CC} = increase in supply current

dc = duty cycle of inputs at a TTL high level of 3.4 V

 C_{pd} = power dissipation capacitance C_L = output capacitive load

C'_L = output capacitive load f_i = data input frequency f_O = data output frequency



APPLICATION INFORMATION

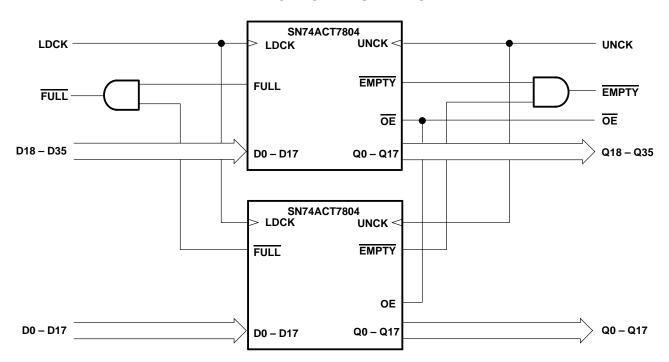


Figure 5. Word-Width Expansion: 512 Words by 36 Bits



PARAMETER MEASUREMENT INFORMATION

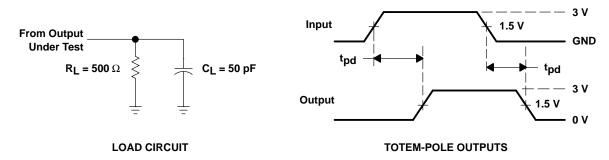
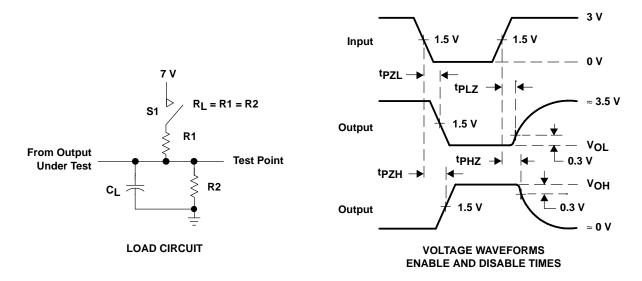


Figure 6. Standard CMOS Outputs (FULL, EMPTY, HF, AF/AE)



PARAI	/IETER	R1, R2	C _L †	S 1	
	^t PZH	500 Ω	50 nE	Open	
^t en	1 $\frac{1211}{\text{tPZL}}$ 500 Ω 50 pF		Closed		
4	^t PHZ	500 Ω	50 nE	Open	
^t dis	tPLZ	500 22	50 pF	Closed	
t _{pd}		500 Ω	50 pF	Open	

[†] Includes probe and test-fixture capacitance

Figure 7. 3-State Outputs (Any Q)

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